Diodes

1W Zener Diode PTZ Series

Applications

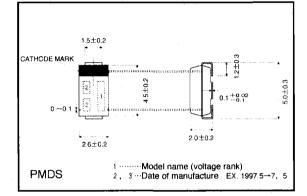
1)Voltage regulation and voltage limiting

2)Voltage surge absorption

Features

Designed for mounting on small surface areas (PMDS)
 W of power can be obtained despite compact size
 High surge withstand level

External dimensions (Units: mm)



Construction

Silicon epitaxial planar

●Absolute maximum ratings (Ta=25°C)

	0.11.1	1 1	L lunit	
Parameter	Symbol	Limits	Unit	
Power dissipation *	Р	1	w	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55~150	ĉ	

* Mounting density of other power components should be taken into consideration when using these products.



●Electrical characteristics (Ta=25°C)

-		Zener voltage subdivision			Operating resistance		Reverse current		
Туре			Vz (V)		Zz	(Ω)	la (μΑ)	
Rank	Rank	Min.	Max.	lz (mA)	Max.	lz (mA)	Max.		
PTZ 3.6	А	3.400	3.800	- 40	15	40			
	В	3.600	4000				60	1.0	
PTZ 3.9	Α	3.700	4.100	40	0 15	40	40	10	
	В	3.900	4.400					1.0	
PTZ 4.3	A	4.000	4.500	40	40 15	40	20	1.0	
	В	4.300	4.800	40	40 15				
PTZ 4.7	А	4.400	4.900	40	10	40	20	1.0	
	в	4.700	5.200						
PTZ 5.1	A	4.800	5.400	40	8	40	20	1.5	
	В	5.100	5.700	+0	0				
PTZ 5.6	А	5.300	6.000	40	8	40	20	1.5	
	В	5.600	6.300	40					
PTZ 6.2	A	5.800	6.600	40	6	40	20	3.0	
	в	6.200	7.000	40					
PTZ 6.8	Α	6.400	7.200	40	c ·	40	20	3.5	
1 12 0.0	В	6.800	7.700		6				
PTZ 7.5	A	7.000	7.900	40	4	40	20	4.0	
1 12 7.5	в	7.500	8.400	40		40			
PTZ 8.2	A	7.700	8,700	40	4	40	20	5.0	
	В	8.200	9.300						
PTZ 9.1	А	8.500	9.600	40	6	40	20	6.0	
P12 9.1	В	9.100	10.200						
PTZ 10	A	9.400	10.600	40	0 6	40	10	7.0	
1 12 10	В	10.000	11.200	-+0					
PTZ 11	A	10.400	11.600	20	8	20	10	8.0	
	В	11.000	12.300	20	o				
PTZ 12	Α	11.400	12.600	20	8		10	0.0	
F 12 12	в	12.000	13.500	20 8	20	10	9.0		
PTZ 13	A	12.400	14.100	20	10	20	10	10.0	
	В	13.300	15.000	20	20 10	10	10 20	10	10.0
PTZ 15	Α	13.800	15.600	20	10	20	10	11.0	
	в	14.700	16.500		20 10				
PTZ 16	Α	15.300	17.100	20	20	12	20	10	12.0
	В	16.200	18.300						
PTZ 18	Α	16.800	19.100	20	20	12	20	10	13.0
	в	18.000	20.300			15.	20	10	10.0
PTZ 20	A	18.800	21.200	20	20	14	20	10	15.0
	В	20.000	22.400			20	14		10
PTZ 22	Α	20.800	23.300	10	14	10	10	17.0	
	в	22.000	24.500		14	10	.0	17.0	

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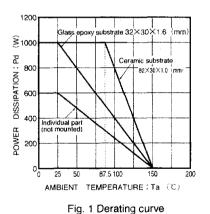
ROHM

Туре		Zener voltage subdivision			Operating resistance		Reverse current		
		Vz (V)		Zz (Ω)		In (μA)			
	Rank	Min.	Max.	lz (mA)	Max.	lz (mA)	Max.	VR (V)	
PTZ 24	A	22.800	25.600	10	16	10	10	19.0	
	В	24.000	27.600						
PTZ 27	A	25.100	28.900	10	16	10	10	21.0	
	в	27.000	30.800						
PTZ 30	A	28.000	32.000	10	18	10	10	23.0	
	в	30.000	34.000						
PTZ 33	A	31.000	35.000	10	10 18	10	10	25.0	
	В	33.000	37.000						
PTZ 36	A	34.000	38.000	10					
	В	36.000	40.000		10 20	10	10	27.0	
PTZ 39	A	37.000	41.000	10	50	10	10	30.0	
PTZ 43	A	40.000	46.000	10	50	10	5	33.0	

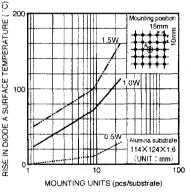
Notes) 1. The Zener voltage is measured 40 ms after power is supplied.

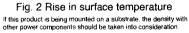
2. The operating resistances (Zz, Zzk) are measured by superimposing a minute alternating current on the regulated current (Iz).

3. For the Zener voltage subdivisions, the free ranks (A, B, or C) or recommended when ordering.



●Electrical characteristic curves (Ta=25°C)





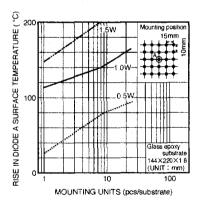
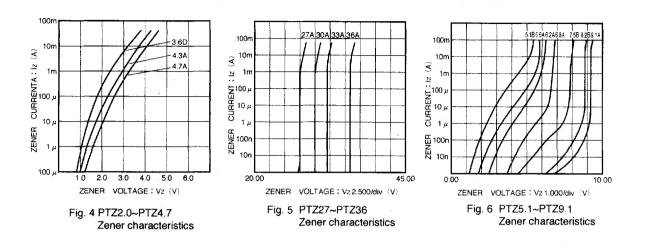
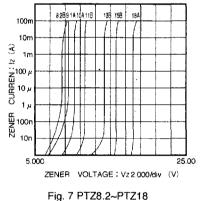


Fig. 3 Rise in surface temperature

Diodes

PTZ Series





Zener characteristics



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